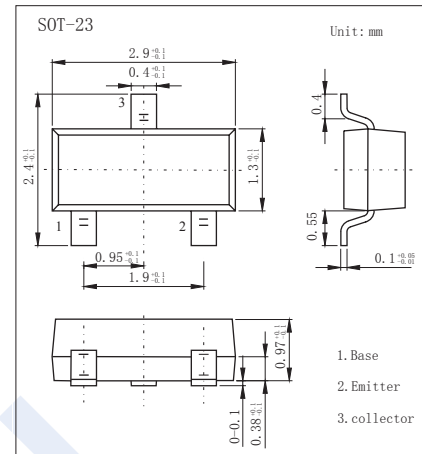


NPN Transistors

MMBTA42 (KMBTA42)

■ Features

- High breakdown voltage
- Low collector-emitter saturation voltage
- Complementary to MMBTA92 (PNP)

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|--|-----------------|------------|---------------------------|
| Collector - Base Voltage | V_{CB0} | 300 | V |
| Collector - Emitter Voltage | V_{CE0} | 300 | |
| Emitter - Base Voltage | V_{EB0} | 5 | |
| Collector Current - Continuous | I_C | 500 | mA |
| Collector Power Dissipation | P_C | 350 | mW |
| Thermal Resistance Junction to Ambient | $R_{\theta JA}$ | 357 | $^\circ\text{C}/\text{W}$ |
| Junction Temperature | T_J | 150 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | -55 to 150 | |

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--------------------------------------|---------------|--|-----|-----|-----|---------------|
| Collector-base breakdown voltage | V_{CB0} | $I_C = 100 \mu\text{A}, I_E = 0$ | 300 | | | V |
| Collector-emitter breakdown voltage | V_{CE0} | $I_C = 1 \text{ mA}, I_B = 0$ | 300 | | | |
| Emitter - base breakdown voltage | V_{EB0} | $I_E = 100 \mu\text{A}, I_C = 0$ | 5 | | | |
| Collector-base cut-off current | I_{CB0} | $V_{CB} = 200 \text{ V}, I_E = 0$ | | | 0.1 | μA |
| Emitter cut-off current | I_{EB0} | $V_{EB} = 5 \text{ V}, I_C = 0$ | | | 0.1 | |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$ | | | 0.2 | V |
| Base - emitter saturation voltage | $V_{BE(sat)}$ | $I_C = 20 \text{ mA}, I_B = 2 \text{ mA}$ | | | 0.9 | |
| DC current gain | $h_{fe} (1)$ | $V_{CE} = 10 \text{ V}, I_C = 1 \text{ mA}$ | 60 | | | |
| | $h_{fe} (2)$ | $V_{CE} = 10 \text{ V}, I_C = 10 \text{ mA}$ | 100 | | 300 | |
| | $h_{fe} (3)$ | $V_{CE} = 10 \text{ V}, I_C = 30 \text{ mA}$ | 60 | | | |
| Transition frequency | f_T | $V_{CE} = 20 \text{ V}, I_C = 10 \text{ mA}, f = 30 \text{ MHz}$ | 50 | | | MHz |

■ Classification of $h_{fe(2)}$

| Type | MMBTA42 | MMBTA42-L |
|---------|---------|-----------|
| Range | 100-300 | 100-200 |
| Marking | 1D | |

NPN Transistors

MMBTA42 (KMBTA42)

■ Typical Characteristics

